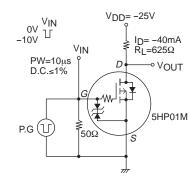
#### 5HP01M

#### Electrical Characteristics at Ta=25°C

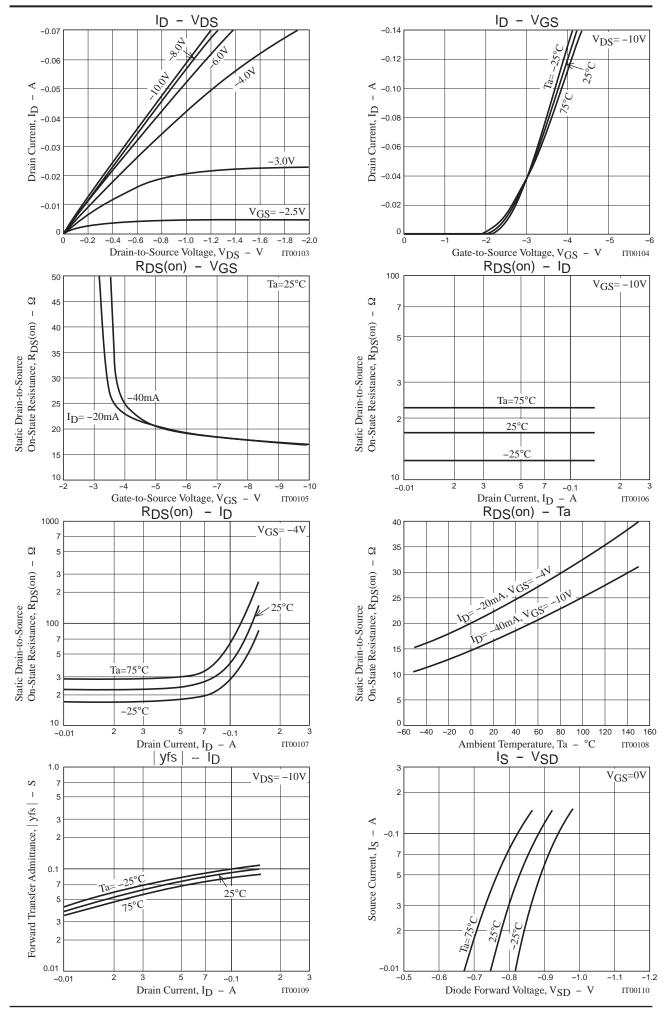
Parameter	Cumbal	Conditions	Ratings			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID= -1mA, VGS=0V	-50			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = -50V, V <sub>GS</sub> =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> = -10V, I <sub>D</sub> = -100μA	-1		-2.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = -10V, I <sub>D</sub> = -40mA	50	70		mS
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> = -40mA, V <sub>GS</sub> = -10V		17	22	Ω
	R <sub>DS</sub> (on)2	I <sub>D</sub> = -20mA, V <sub>GS</sub> = -4V		23	32	Ω
Input Capacitance	Ciss			6.2		pF
Output Capacitance	Coss	V <sub>DS</sub> = -10V, f=1MHz		4.0		pF
Reverse Transfer Capacitance	Crss			1.3		pF
Turn-ON Delay Time	t <sub>d</sub> (on)			13		ns
Rise Time	t <sub>r</sub>	Sac appointed Toot Circuit		10		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		100		ns
Fall Time	tf			150		ns
Total Gate Charge	Qg			1.32		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> = -10V, V <sub>GS</sub> = -10V, I <sub>D</sub> = -70mA		0.17		nC
Gate-to-Drain "Miller" Charge	Qgd			0.34		nC
Diode Forward Voltage	VSD	I <sub>S</sub> = -70mA, V <sub>G</sub> S=0V		-0.85	-1.2	V

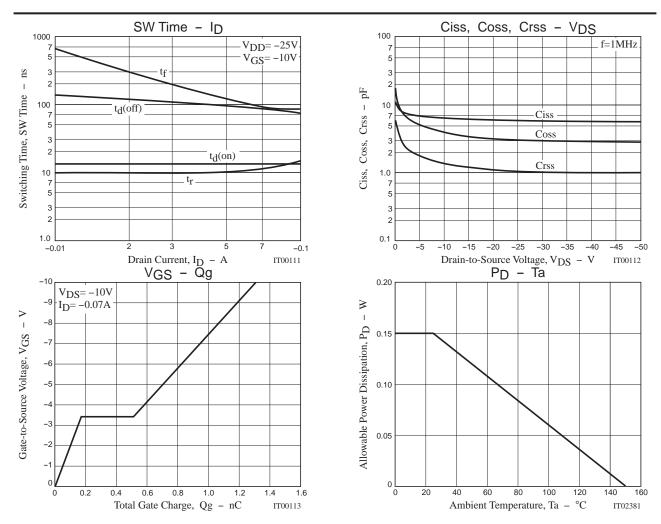
# Switching Time Test Circuit



# **Ordering Information**

Device	Package	Shipping	memo	
5HP01M-TL-E	MCP	3,000pcs./reel	Pb Free	
5HP01M-TL-H	MCP	3,000pcs./reel	Pb Free and Halogen Free	

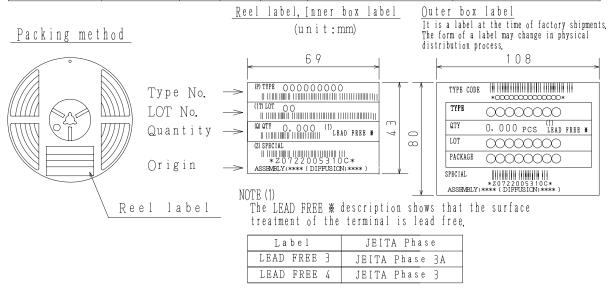




# Embossed Taping Specification 5HP01M-TL-E, 5HP01M-TL-H

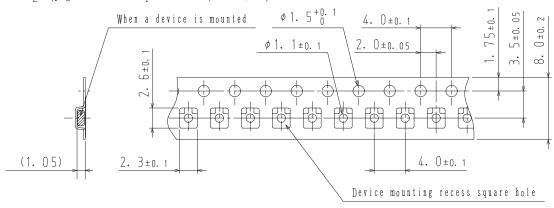
#### 1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
MCP	MCP	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	

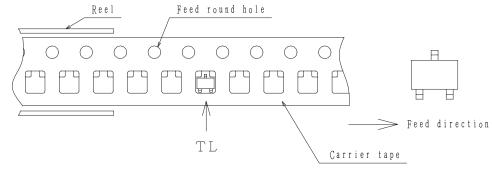


#### 2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



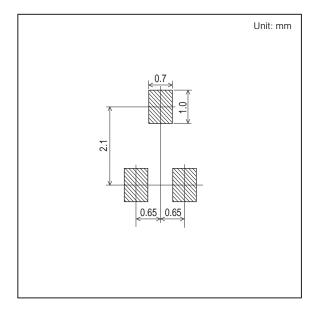
Those with oen electrode terminal on the feed hole side·····TL

# **Outline Drawing**

#### 5HP01M-TL-E, 5HP01M-TL-H

# 

#### **Land Pattern Example**



Note on usage: Since the 5HP01M is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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